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Kawabe

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(54) **DISPLAY DEVICE**

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G09G 3/30 (2006.01)
G09G 3/32 (2006.01)

(52) **U.S. Cl.** 345/76; 345/82

(58) **Field of Classification Search** 345/87-100,
345/76, 77, 82, 83, 204
See application file for complete search history.

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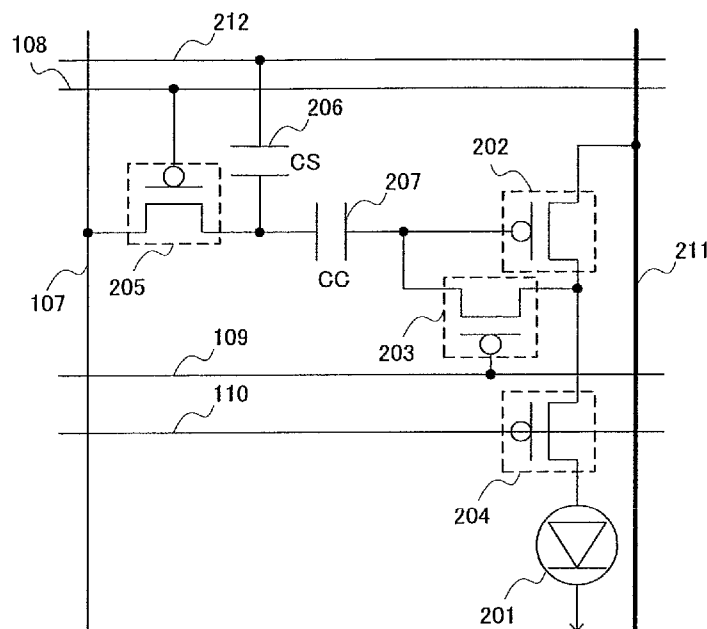
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(57) **ABSTRACT**

An active matrix type display device includes array having pixel circuits arranged in rows and columns matrix form, each pixel circuit includes a current-driven diode type light-emitting element and a plurality of thin-film transistor for controlling the diode type light-emitting element; a data line provided for each column of the matrix for supplying a data signal to the pixel circuits on the corresponding column; a data driver for controlling the supply of the data signal to the data line; a gate line provided for each row of the matrix for supplying a selection signal to pixel circuits on the corresponding row; a gate driver for supplying a selection signal to the gate line; and a control circuit for controlling the data driver and gate driver, wherein the data driver switches a plurality of sets of video signals alternately and supplies the video signals to the data line.

3 Claims, 16 Drawing Sheets



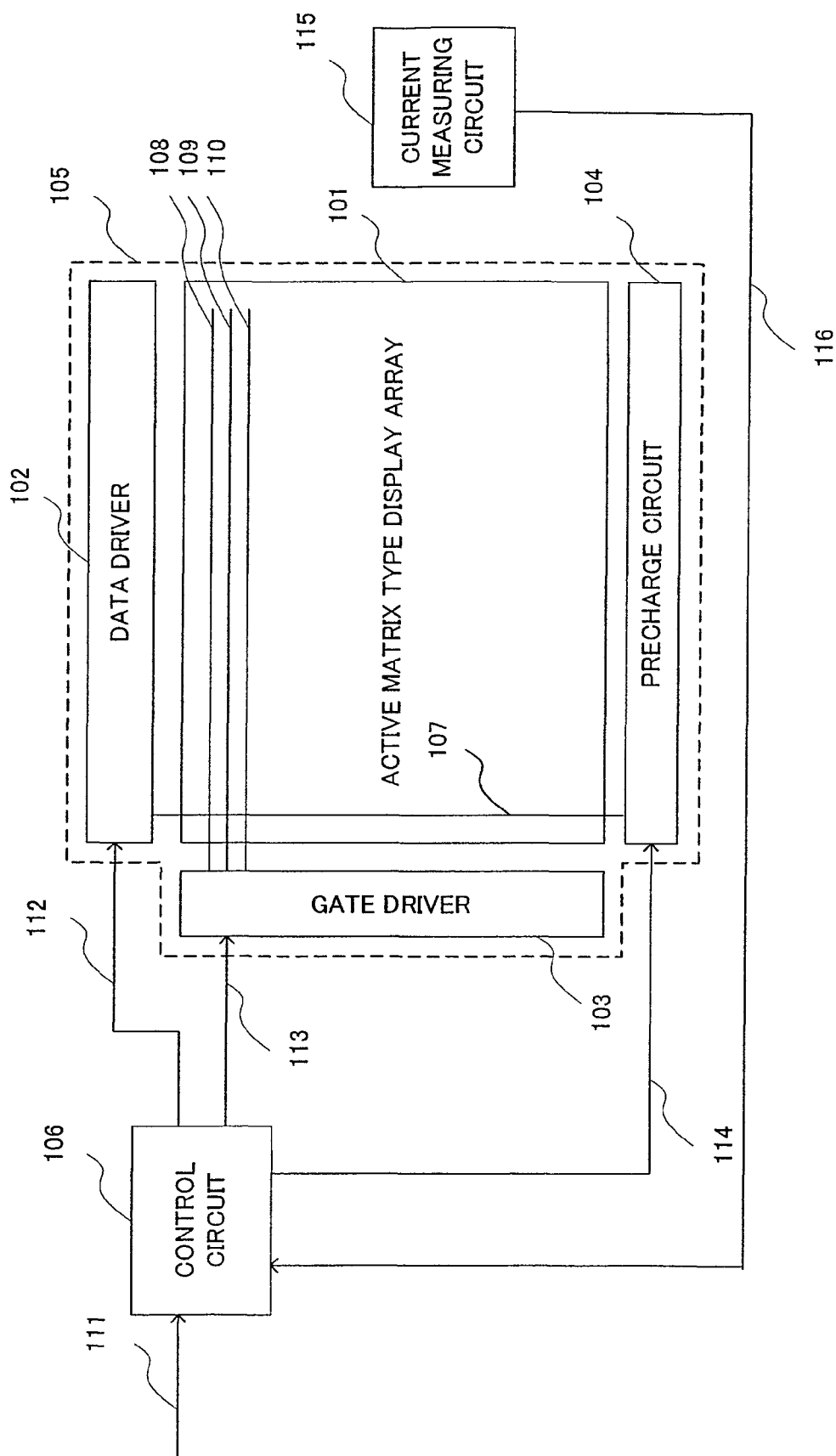


Fig. 1

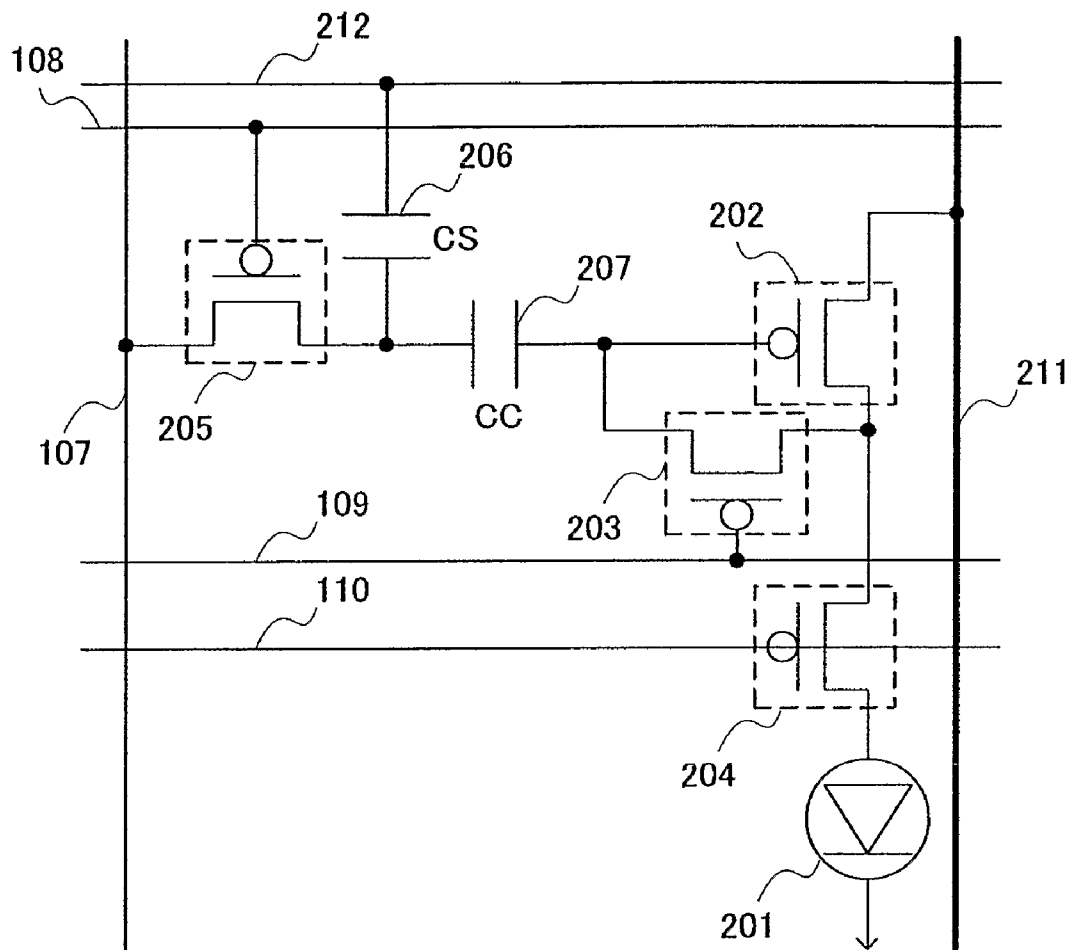


Fig. 2

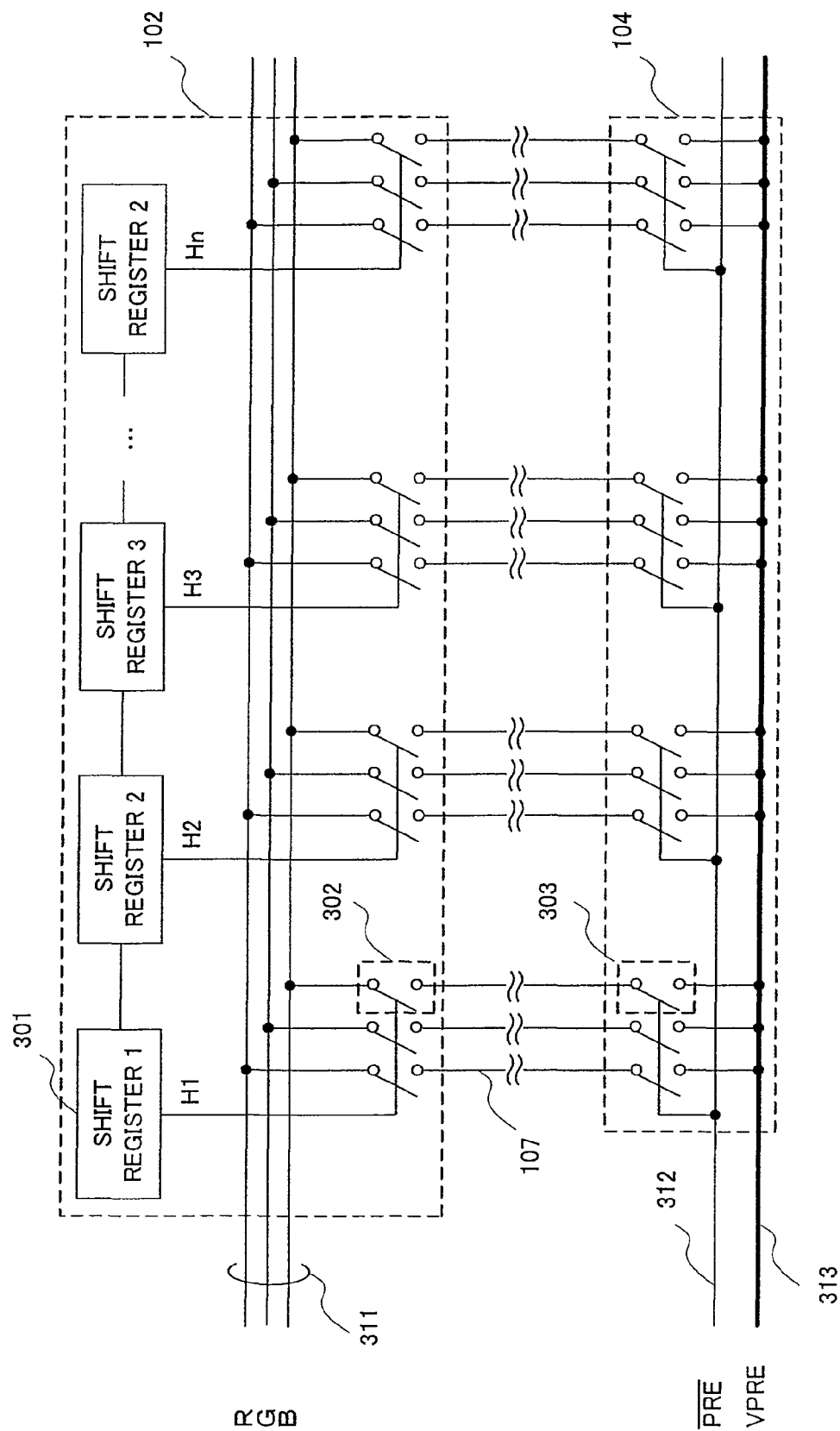


Fig. 3

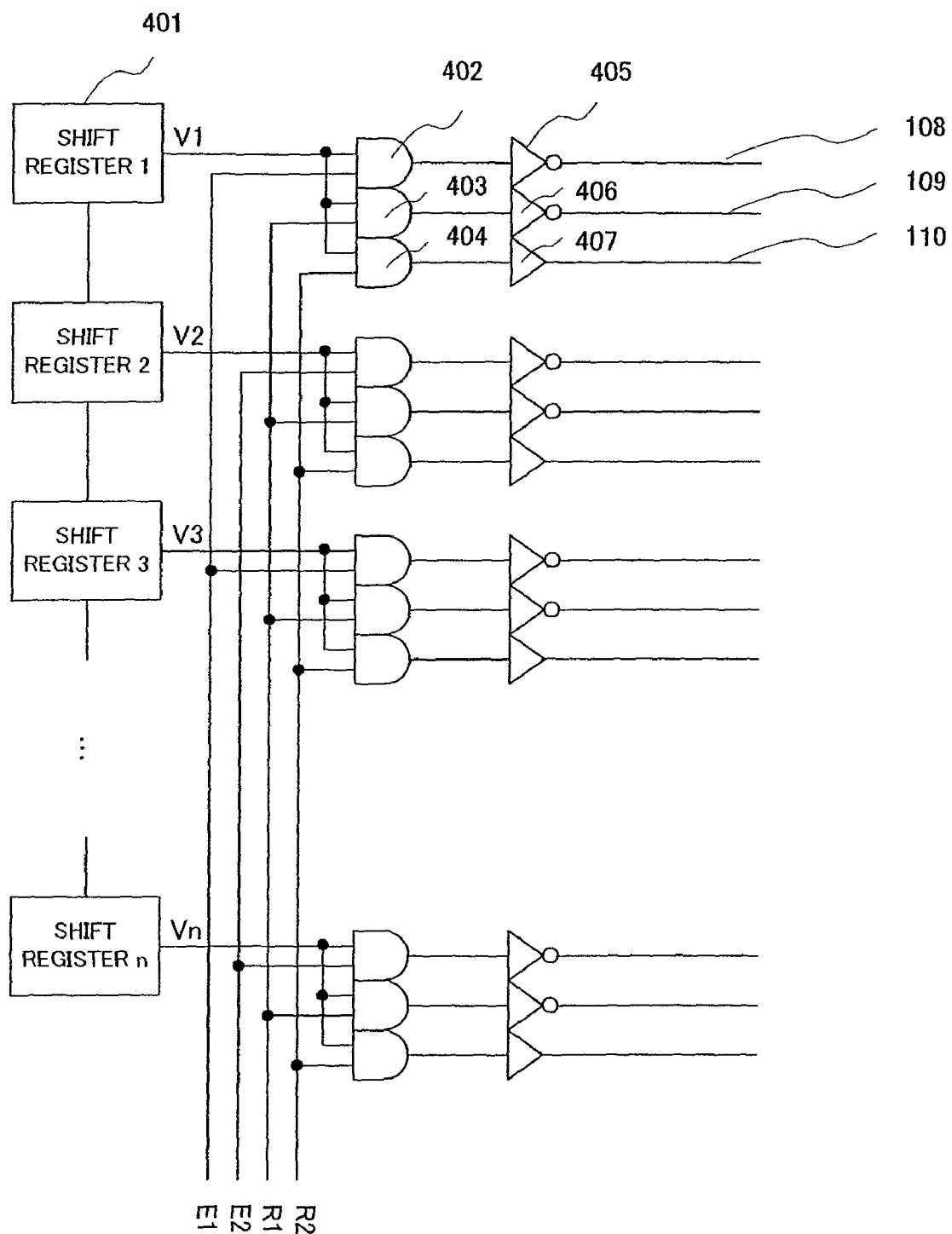
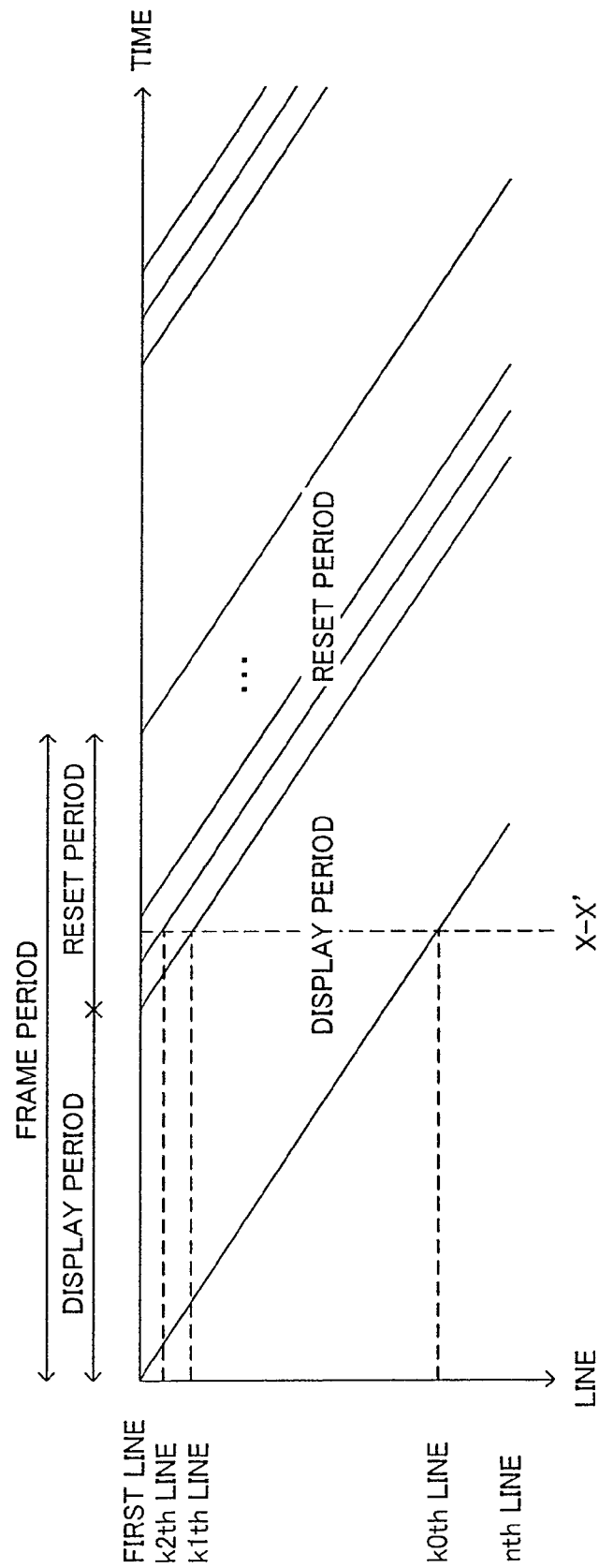


Fig. 4



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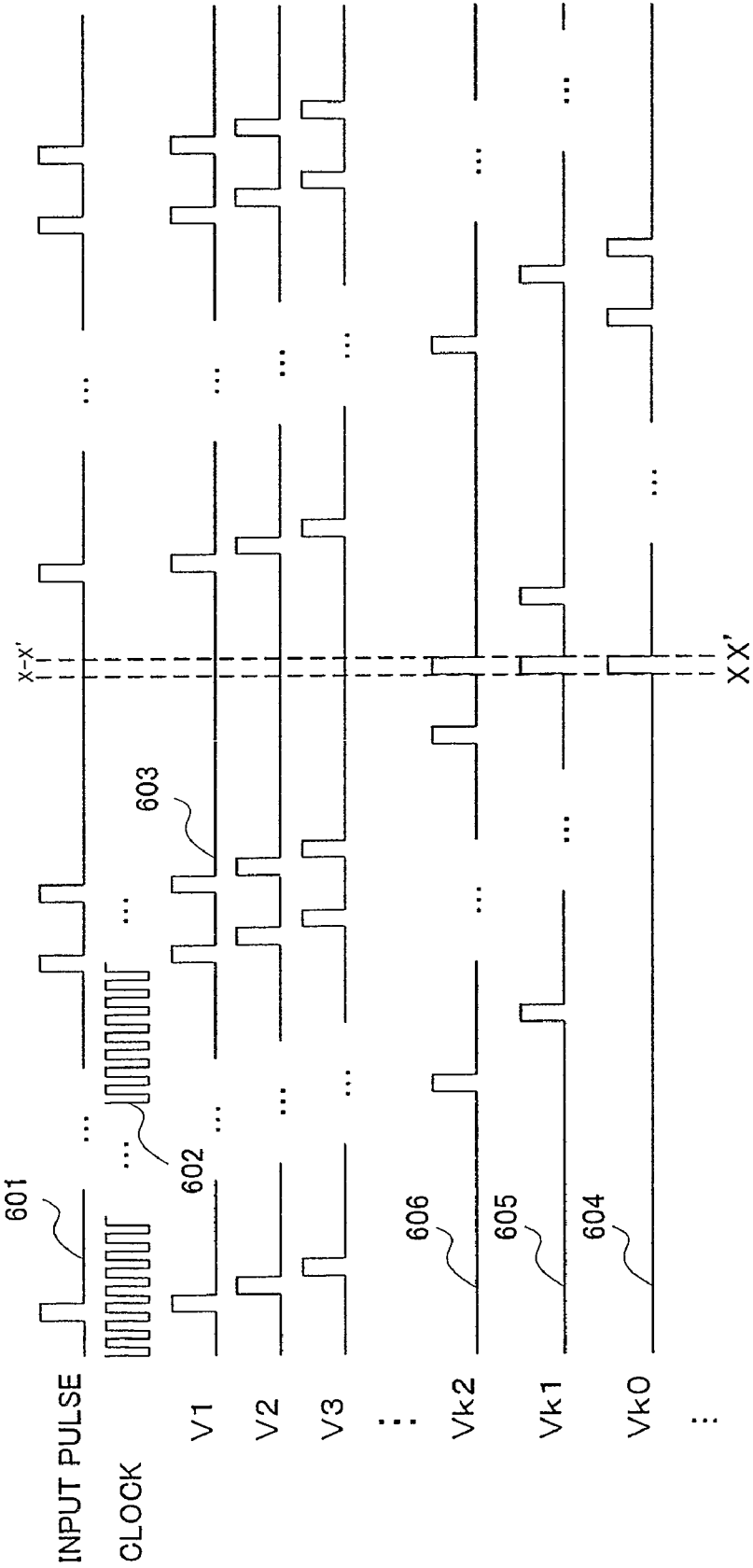


Fig. 6

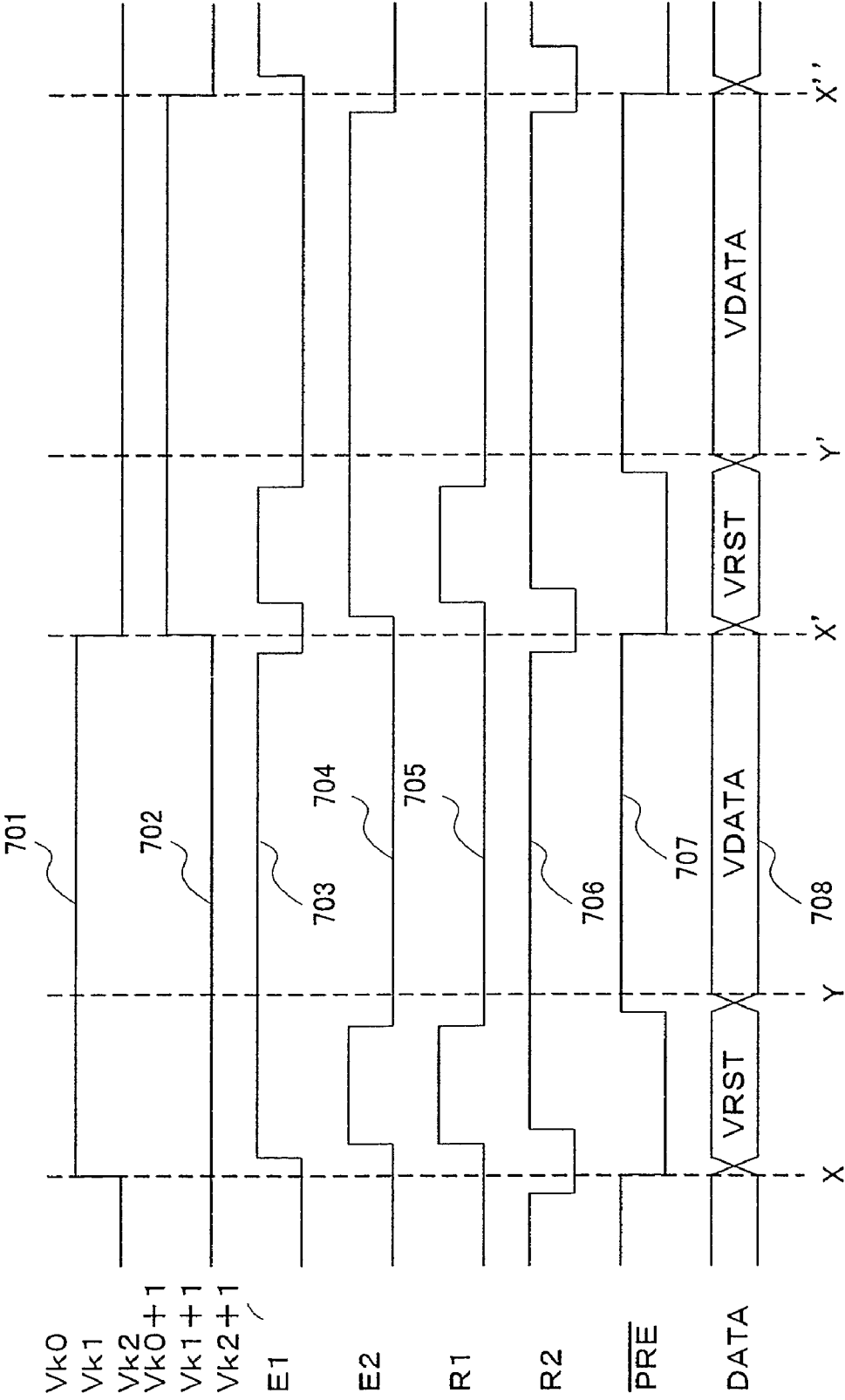
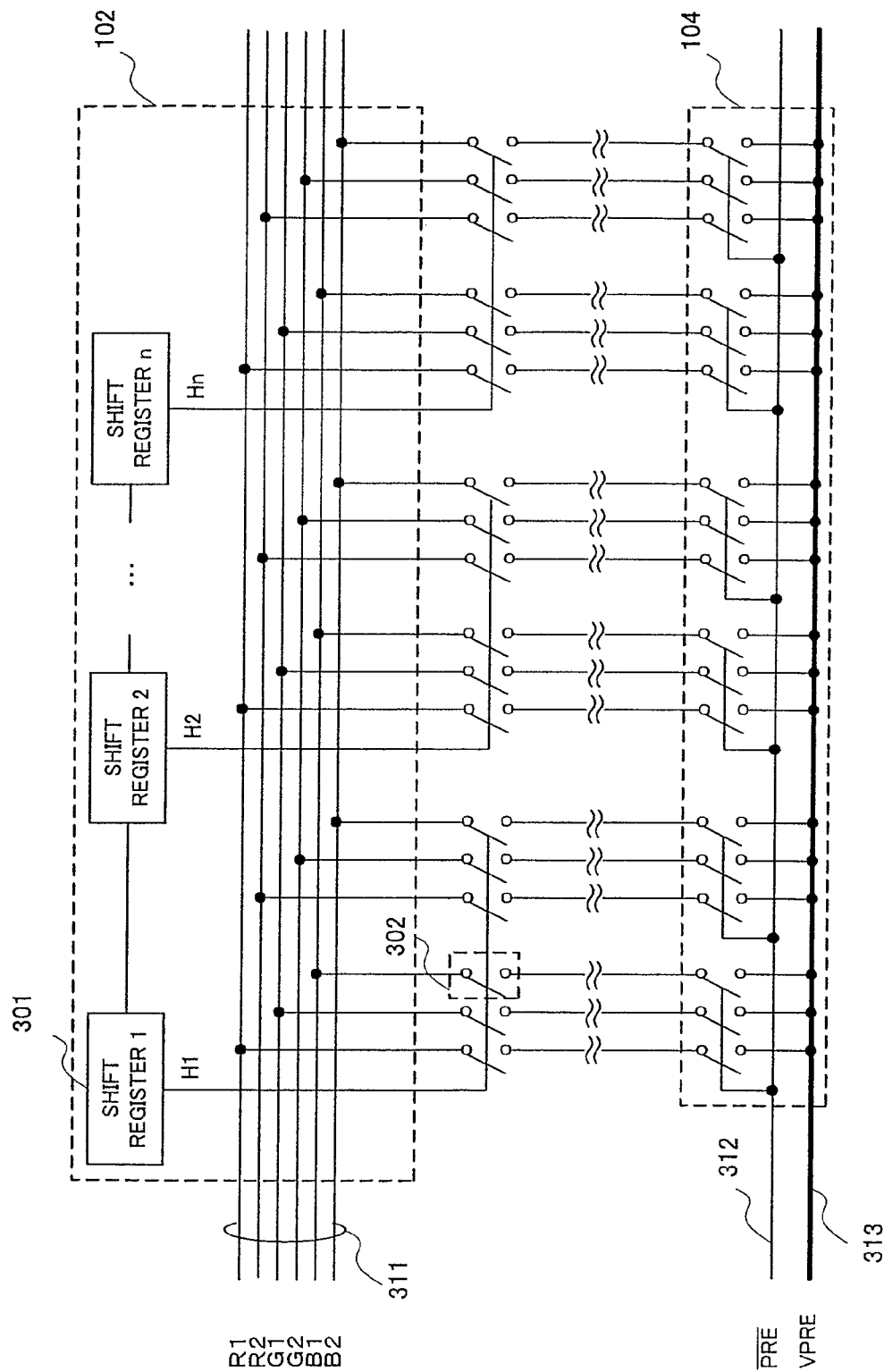


Fig. 7

		V2n-1	V2n	E1	E2	R1	R2	$\overline{\text{PRE}}$	DATA
(1)	(2n-1)TH LINE RESET	H	—	H	—	H	H	L	VRST
(2)	(2n-1)TH LINE DATE WRITE	H	—	H	—	L	H	H	VDATA
(3)	(2n-1)TH LINE ON	L	—	—	—	—	—	—	—
(4)	2nTH LINE RESET	—	H	—	H	H	H	L	VRST
(5)	2nTH LINE DATE WRITE	—	H	—	H	L	H	H	VDATA
(6)	2nTH LINE ON	—	L	—	—	—	—	—	—

— don't care

Fig. 8



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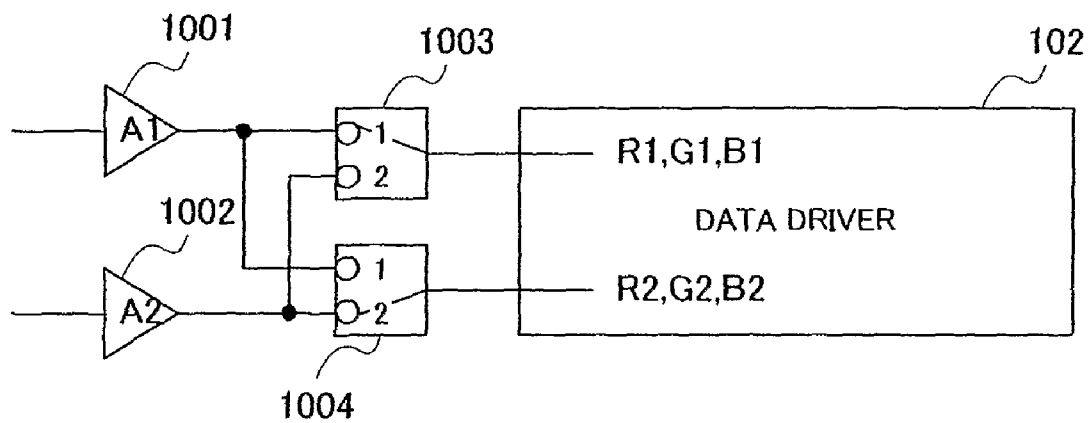


Fig. 10

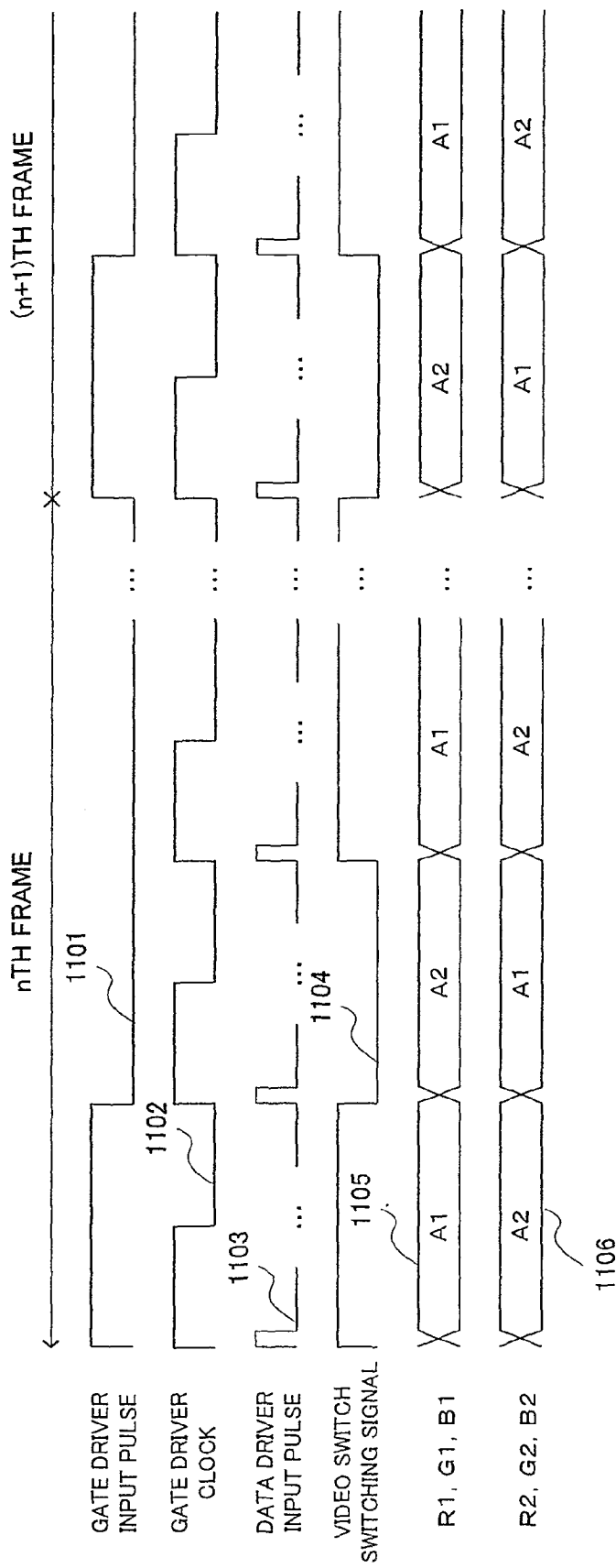


Fig. 11

PRIOR ART

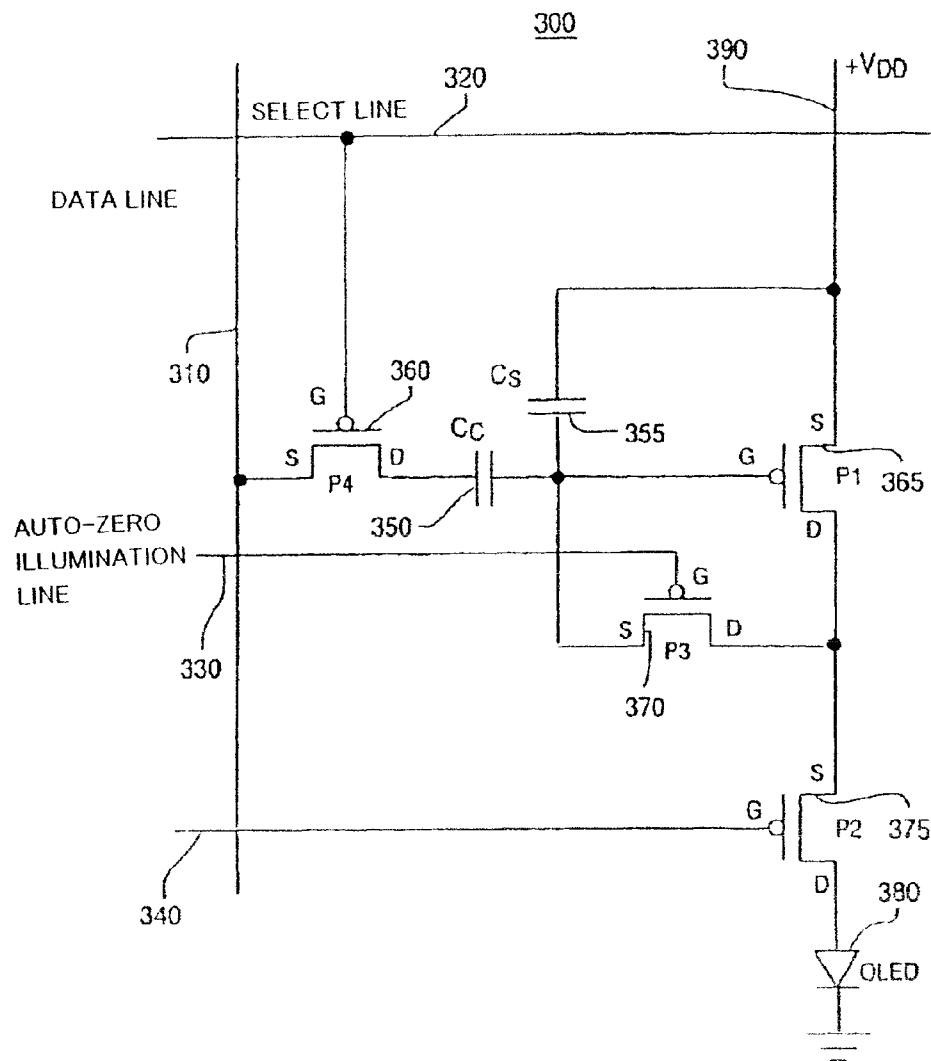


Fig. 12

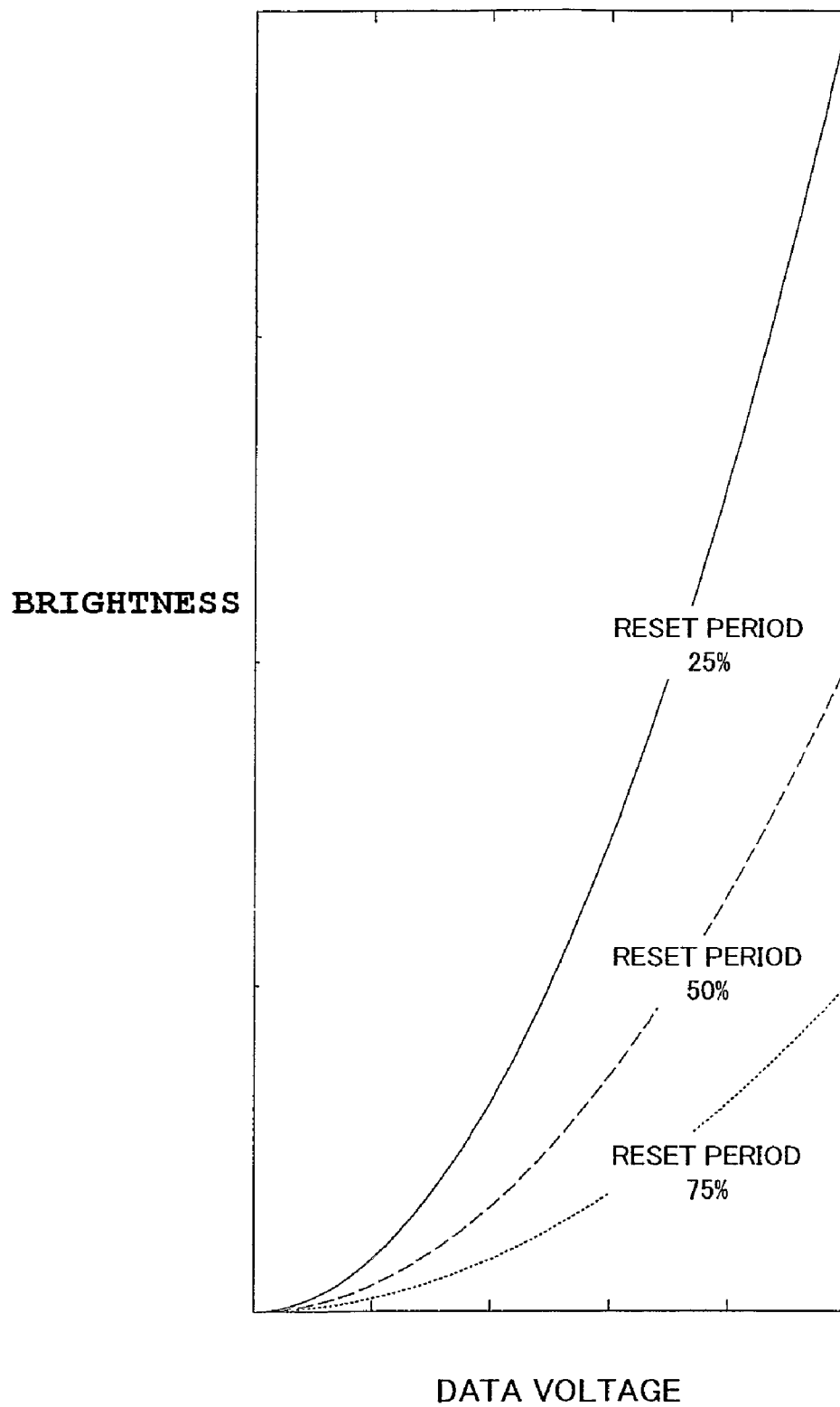


Fig. 13

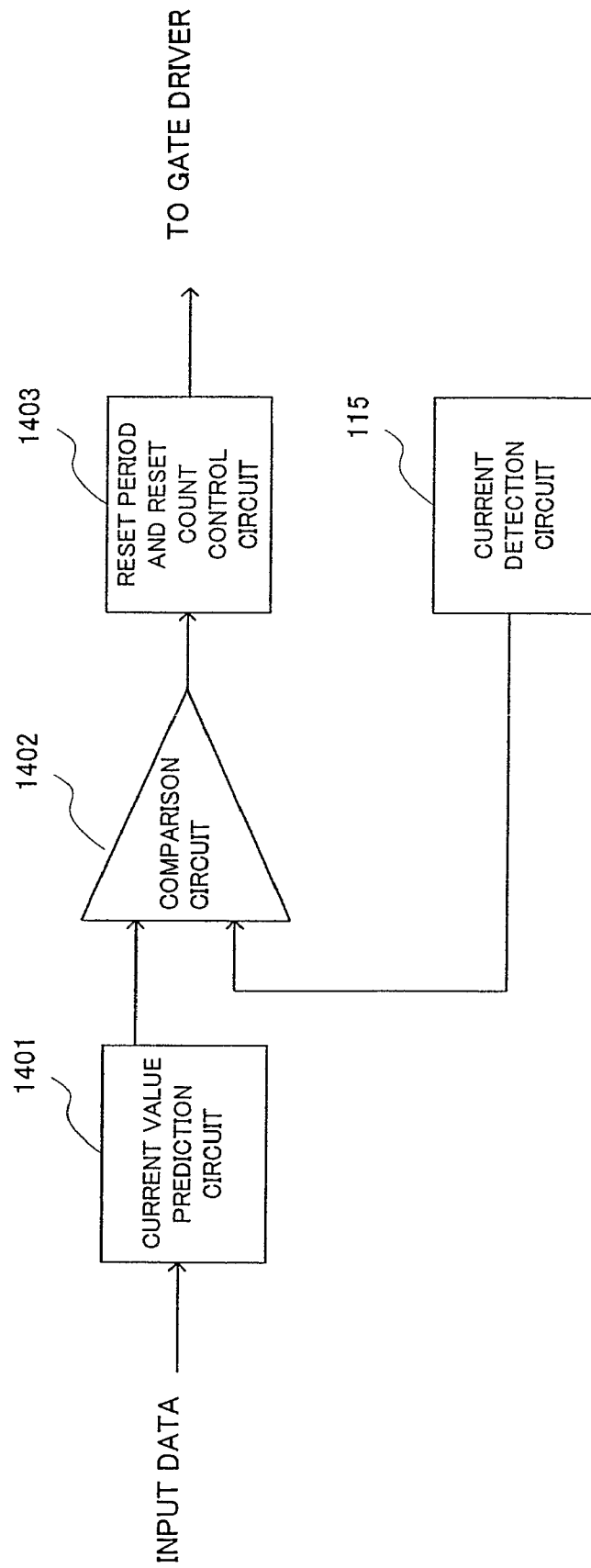


Fig. 14

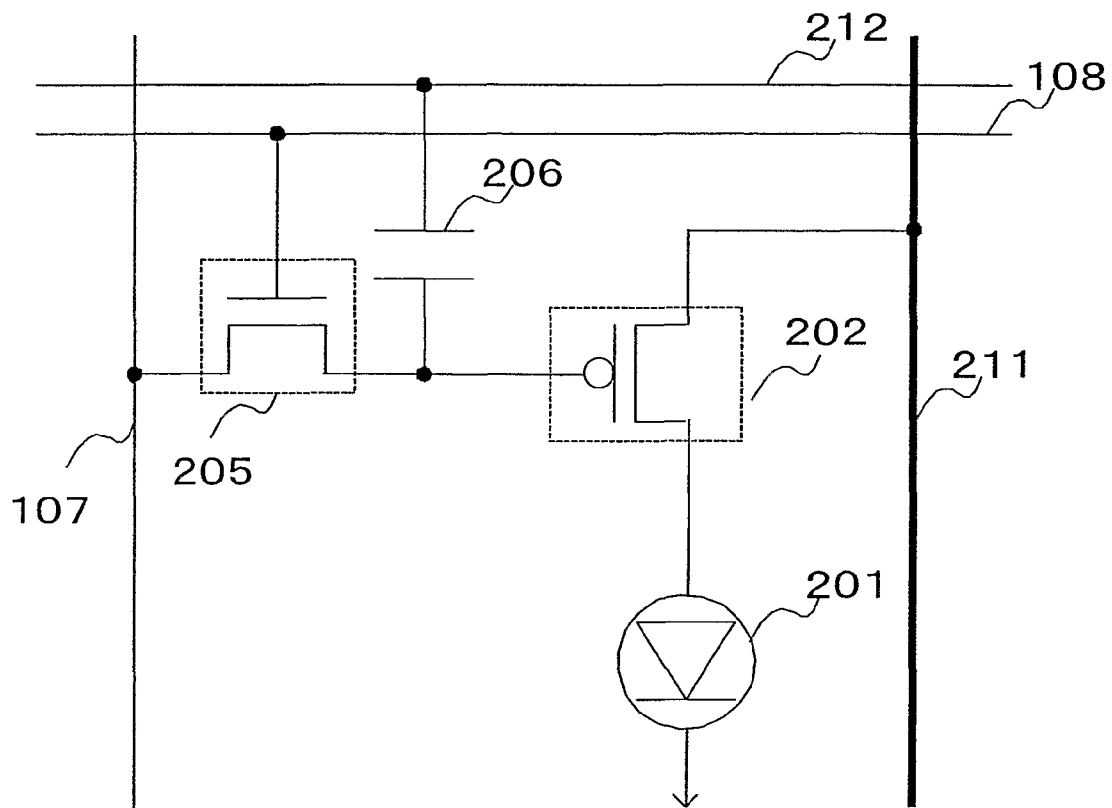


Fig. 15

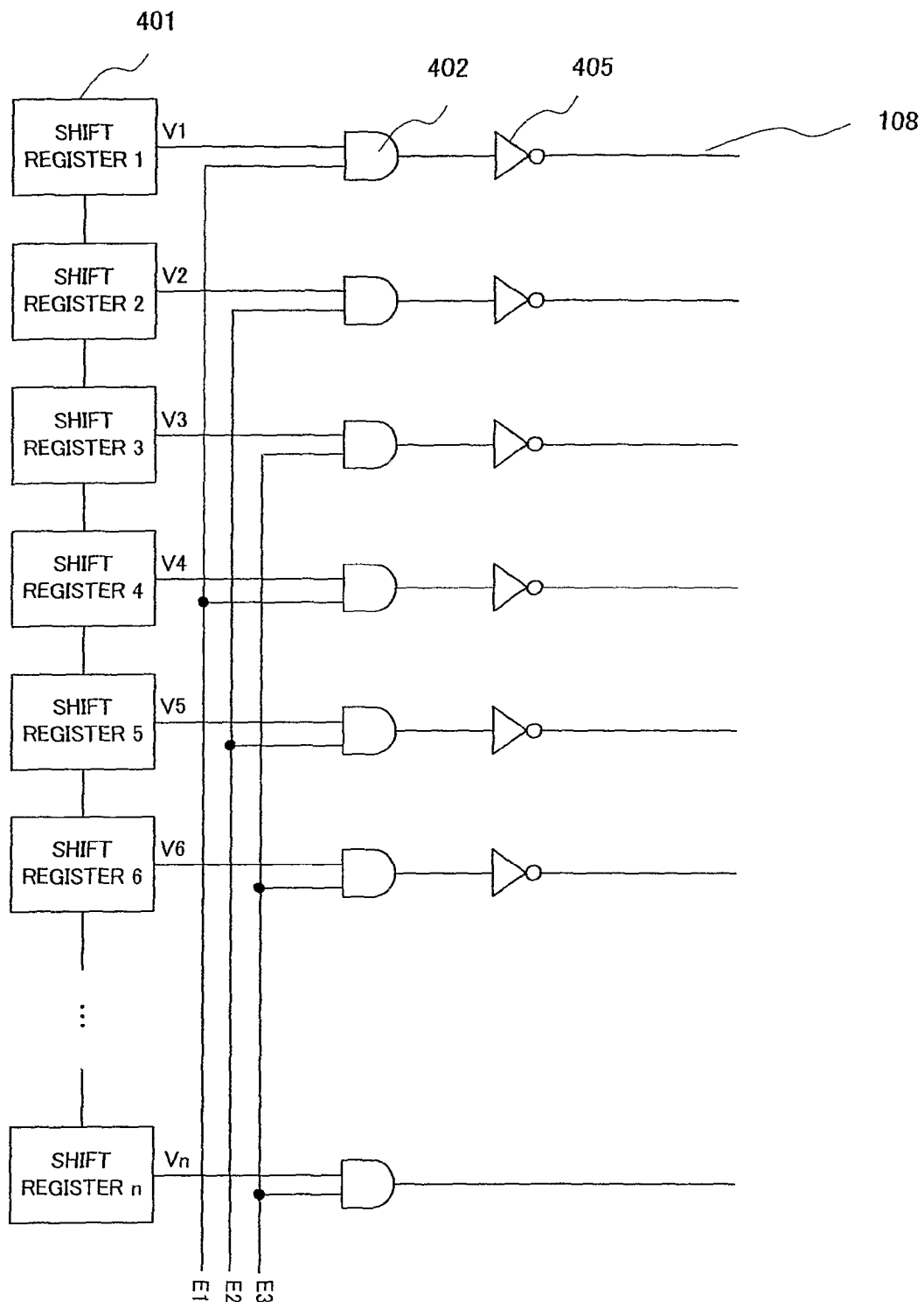


Fig. 16

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DISPLAY DEVICE

FIELD OF THE INVENTION

The present invention relates to an active matrix type display device, and more particularly to one using current driven diode type light-emitting elements.

BACKGROUND OF THE INVENTION

With the progress of computerization in recent years, even portable information terminals are required to have a processing capacity comparable to that of a personal computer in the past. In line with this trend, there is also a demand for video display devices with high definition, high quality and preferably with low-profile, light weight, wide viewing angle and low power consumption.

In response to these requests, a display device with thin-film active elements (thin-film transistor, simply referred to as "TFT") formed on a glass substrate in matrix form and electro-optic elements formed thereon is being actively developed.

The mainstream of the substrates on which active elements are formed is one with a semiconductor film of amorphous silicon or poly-silicon, etc., formed, patterned and connected with metal wires. Due to differences in electrical characteristics of active elements, the former requires a driving IC (Integrated Circuit) and the latter features the ability to allow a drive circuit to be formed on the substrate.

While the former, the amorphous silicon type, is popular for large liquid crystal displays (simply referred to as "LCD") currently being widely used, the latter, the poly-silicon type, is becoming the mainstream for medium or small liquid crystal displays.

Only poly-silicon type electro-luminescence type (organic EL) displays featuring self-light-emission, thin, lightweight and wide view-angle are being mass-produced.

An organic EL element is generally combined with a TFT and a current is controlled using a voltage/current control action thereof. Here, the voltage/current control action refers to an action of controlling a current between the source and drain by applying a voltage to the gate terminal of the TFT. By so doing, it is possible to adjust light-emitting intensity and display desired gradation.

The use of such a structure, however, causes the light-emitting intensity of the organic EL element to be quite sensitive to being affected by TFT characteristics. In particular, poly-silicon TFT, poly-silicon TFT formed in a low-temperature process called "low-temperature poly-silicon" is above all confirmed to generate relatively large differences in electrical characteristics between adjoining pixels, which constitutes one of the major causes for the deterioration of the display quality of the organic EL display, particularly display uniformity in the screen.

As shown in FIG. 12, the prior art discloses means for correcting a threshold voltage of a poly-silicon TFT 365 which drives an organic EL element.

With an illumination line 340 and auto-zero illumination line 330 set to L levels to turn ON TFT 375 and TFT 370, a select line 320 is set to L level to set a data line 310 to a reference voltage which is higher than a maximum voltage of a data signal. In this way, the gate voltage of a TFT 365 is set to a threshold voltage of the TFT 365. As a result, the difference between a threshold voltage V_{th} and the reference voltage is charged in a capacitance 350 and the difference between the threshold voltage V_{th} and supply voltage $+V_{dd}$ is charged in a capacitance 355.

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Next, the illumination line 340 and auto-zero illumination line 330 are set to H level to turn OFF the TFT 375 and TFT 370 and the data signal is set in the data line 340 in this condition. This causes the gate voltage of the TFT 365 to be shifted. This gate voltage corresponds to the threshold voltage of the TFT 365 and this gate voltage can compensate for the threshold voltage of the TFT 365 for each pixel.

Then, the illumination line 340 is set to L level to turn ON the TFT 375, a current corresponding to the gate voltage to which the TFT 365 is set is supplied to an OLED 380 and the OLED 380 emits light. Furthermore, even after the select line 320 is set to H level, the gate voltage of the TFT 365 is kept to the same voltage and the current corresponding to the data signal flows into the OLED 380.

That is, in the prior art shown in FIG. 12, a potential V_g applied to the gate terminal of the TFT 365 is expressed by $V_g = V_{th} + V_d * C_c / (C_c + C_s)$, where V_{th} is the threshold voltage of the TFT 365, V_d is a gradation voltage and C_c , C_s are capacitance values shown in FIG. 12. Thus, since the threshold voltage V_{th} of the TFT 365 of each pixel is always added to V_g , it is possible to give an offset to V_g without changing the gradation voltage V_d even if V_{th} differs from one pixel to another.

SUMMARY OF THE INVENTION

In the circuit in FIG. 12, the data line can be driven using the signal from the shift register, but it is expected to realize a higher definition display on the basis of such a driving method.

The present invention is an active matrix type display device comprising an active matrix type display array made up of pixel circuits arranged in a matrix form, each pixel circuit made up of a current-driven diode type light-emitting element and a thin-film transistor for controlling the diode type light-emitting element, a data line provided for each column of the matrix for supplying a data signal to the pixel circuits on the corresponding column, a data driver for controlling the supply of the data signal to the data line, a gate line provided for each row of the matrix for supplying a selection signal to pixel circuits on the corresponding row, a gate driver for supplying a selection signal to the gate line and a control circuit for controlling the data driver and gate driver, wherein the data driver switches a plurality of sets of video signals alternately and supplies the video signals to the data line.

In the present invention, the data driver preferably further switches between the plurality of sets of video signals at least for each frame or each line and supplies the video signals to the data line. According to one embodiment of the present invention, the plurality of sets of video signals include a first set and second set, in the data driver, for an odd frame, the first data line on an odd line supplies the first set video signals, the second data line of the same color adjoining the first data line supplies the second set video signals, the first data line on an even line supplies the second set video signals and the second data line supplies the first set video signals, and for an even frame, the first data line on an odd line supplies the second set video signals, the second data line supplies the first set video signals, the first data line on an even line supplies the first set video signals and the second data line supplies the second set video signals.

The present invention provides a plurality of video signals and drives data lines by switching between the plurality of video signals alternately, and can thereby realize a high defi-

niton display. Furthermore, the invention switches and drives the video signals alternately, and can thereby suppress flickering as well.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is an overall block diagram according to Embodiment 1;

FIG. 2 illustrates a structure of a pixel circuit;

FIG. 3 illustrates a data driver and a precharge circuit according to Embodiment 1;

FIG. 4 is a block diagram of a gate driver;

FIG. 5 illustrates a drive sequence;

FIG. 6 is a panel drive timing chart;

FIG. 7 is an enlarged view of the panel drive timing chart;

FIG. 8 is an operation table showing operations of pixel circuits on each row;

FIG. 9 illustrates a data driver and precharge circuit according to Embodiment 2;

FIG. 10 illustrates a structure of a display variation smoothing circuit;

FIG. 11 is a drive timing chart of the display variation smoothing circuit;

FIG. 12 illustrates a pixel circuit of a conventional example;

FIG. 13 illustrates a relationship between a reset period and brightness;

FIG. 14 illustrates a structure of control based on a current measured value;

FIG. 15 illustrates another example of the structure of the pixel circuit; and

FIG. 16 illustrates another example of the structure of the gate driver.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

With reference now to the attached drawings, embodiments of the present invention will be explained in detail below.

Embodiment 1

FIG. 1 is an overall block diagram of an organic EL display according to this embodiment. Reference numeral **101** denotes an active matrix type display array with organic EL elements and TFTs arranged on pixels arranged in a matrix form, **102** denotes a data driver, **103** denotes a gate driver (selection driver) and **104** denotes a precharge circuit.

Reference numeral **107** denotes a data line which supplies a data potential from the data driver **102** or a precharge potential from the precharge circuit **104** to pixels, **108** denotes a gate line (selection line) which supplies a gate selection potential from the gate driver, and **109**, **110** respectively denote a first reset line and a second reset line which supply reset potentials from the gate driver.

If, for example, a low-temperature poly-silicon process is applied, these circuits can be constructed on a glass substrate and a display device **105** can be formed.

Reference numeral **106** denotes a control circuit which supplies an analog video signal and a control signal to the data driver **102** through a data control bus **112** and supplies a control signal to the gate driver **103** through a gate control bus **113**.

Reference numeral **115** denotes a current measuring circuit which detects an amount of current which flows into the active matrix type display array **101**, varying depending on

the magnitude of light-emitting brightness, and which sends the amount of current to the control circuit **106** through a signal line **116**. This current measuring circuit **115** measures all currents flowing into the active matrix type display array **101** and the current measuring circuit **115** can be an ammeter disposed between the active matrix type display array **101** and a power supply or an ammeter disposed between the active matrix type display array **101** and ground.

The operation of such an organic EL display will be explained briefly. The data driver **102** selects one data line **107** for one horizontal period and supplies a data potential for a second-half period of one horizontal period. On the other hand, the precharge circuit **104** selects the same data line **107** as that of the data driver **102** and supplies a preset potential for the first-half period of one horizontal period.

Furthermore, the gate driver **103** selects one gate line **108** every one horizontal period sequentially and supplies a reset signal to the corresponding first reset line **109** and the second reset line **110**. This causes a data writing operation to be performed for the pixel circuits on the corresponding row after a reset operation.

Furthermore, in this embodiment, it is possible to set a row on which only reset is performed not on a row on which the above described data write is performed. That is, the gate line **108** on another row can also be selected only when the preset potential for the first-half period is supplied, simultaneously with the above described row. Therefore, such a selection of another row allows the pixel circuits on the corresponding row to be only reset. Therefore, setting a period after the above described data write is performed until reset is performed allows the display period to be set arbitrarily. The operation will be explained more specifically later.

The structure of the pixel circuit of the present invention arranged in a matrix form in the active matrix type display array **101** will be explained using FIG. 2.

Reference numeral **201** denotes an organic EL element, **202** denotes a drive TFT which drives the organic EL element **201**, **203** denotes a reset TFT which short-circuits the gate and the drain of the drive TFT **202** and converts the drive TFT **202** into a diode and **204** denotes a drive control TFT which turns OFF the current which flows into the organic EL **201**.

Reference numeral **205** denotes a selection TFT which supplies and controls a data potential from the data line **107** into a pixel, **206** denotes a storage capacitance which stores a data potential of the data line **107** and **207** denotes a reset capacitance which stores a reset potential.

Reference numeral **211** denotes a power line which supplies a current to the organic EL element **201** and **212** denotes a fixed potential line which fixes the potential of one terminal of the storage capacitance.

The source terminal of the drive TFT **202** is connected to the power line **211**, the drain terminal is connected to the source terminal of the drive control TFT **204** and the source terminal of the reset TFT **203**, and the gate terminal is connected to one terminal of the reset capacitance **207** and the drain terminal of the reset TFT **203**.

The gate terminal of the reset TFT **203** is connected to the first reset line **109**, the gate terminal of the drive control TFT **204** is connected to the second reset line **110** and the drain terminal of the drive control TFT **204** is connected to the anode of the organic EL element **201**.

The gate terminal of the selection TFT **205** is connected to the gate line **108**, the drain terminal is connected to the data line **107** and the source terminal is connected to one terminal of the storage capacitance **206** and one terminal of the reset capacitance **207**.

The selection TFT **205**, drive TFT **202**, reset TFT **203** and drive control TFT **204** are all p-channel TFTs. However, these TFTs **205**, **203**, **204** may also have n channels.

In such a pixel circuit, the gate line **108** and first reset line **109** are set to L level and the second reset line **110** is shifted from L level to H level first. This causes the selection TFT **205** to turn ON, causes the reset TFT **203** to turn ON and causes the drive control TFT **204** to shift from ON to OFF. Furthermore, the voltage of the data line **107** is set to a precharge potential. Therefore, the drive TFT **202** is diode-connected and a current flows from the power line **211** to the organic EL **201** through the current drive TFT **202** and drive control TFT **204**, and then the drive control TFT **204** turns OFF. When the reset TFT **203** turns ON and the drive TFT **202** is diode-connected, the gate voltage of the drive TFT **202** is set to a voltage lower than the voltage of the power line **211** by a threshold voltage of the drive TFT **202**. On the other hand, the other end of the reset capacitance **207** is set to a precharge potential and a voltage corresponding to the difference between the two is charged in the reset capacitance **207**. The difference between the fixed potential of the fixed potential line **212** and the precharge potential is charged in the storage capacitance **206**.

Next, the reset lines **109**, **110** are set to H level, the reset TFT **203** and drive control TFT **204** are turned OFF, and then a data potential is supplied to the data line **107**. In this way, the potential of the reset capacitance **207** on the gate TFT **205** side is set to the data potential and a voltage corresponding to the difference between the data potential and fixed potential is charged in the storage capacitance **206** and this voltage is stored in the storage capacitance **206**. On the other hand, the gate voltage of the drive TFT **202** is shifted by the difference between the precharge potential and data potential. For example, if the gate voltage is V_g , the precharge voltage is V_{pr} , the data voltage is V_D , the voltage of the power line **211** is V_{DD} and the threshold voltage of the drive TFT **202** is V_{th} , then $V_g = V_{th} - (V_{pr} - V_D)$.

Thus, since the gate voltage of the drive TFT **202** can be set to a voltage according to the threshold voltage of the drive TFT **202** and data potential, the drive control transistor **204** is turned ON with the second reset line set to L level and when one horizontal period ends, the gate TFT **205** is turned OFF with the gate line **108** set to H level. In this way, the drive TFT **202** is driven by the gate voltage which has been set as described above, the drive current is supplied to the organic EL **201** and the organic EL **201** emits light driven by the drive current which compensates for the threshold voltage of the drive TFT **202**.

The structures of the data driver **102** and precharge circuit **104** will be explained using FIG. 3.

Reference numeral **301** denotes a shift register, **302** denotes a video switch, **311** denotes video signal lines and the data driver **102** in FIG. 3 shows a data driver structure corresponding to one set of RGB.

The shift register **301** shifts an input pulse (e.g., one H level) sequentially from the shift register **1** to n in synchronization with a predetermined clock. A pulse resulting from shifting the input pulse to the shift register **1** to n is output to an output terminal H_i ($i=1$ to n), the video switch **302** is controlled (turned ON sequentially) by this pulse, and the corresponding video signal is output to the corresponding data line **107** and sampled-and-held.

Furthermore, the precharge circuit **104** is constructed of a precharge switch **303**, a precharge control line **312** and a precharge line **313**, and it is possible to charge the precharge potential supplied to the precharge line **313** into the data lines

107 through a single line in a collective manner by controlling the precharge control line **312**.

That is, an input pulse is shifted sequentially from the shift register **1** to n for one horizontal period and video signals from the three video signal lines of RGB are supplied to the data lines **107** sequentially corresponding to the second-half period of one horizontal line. In this example, there are R (red), G (green) and B (blue) pixels each forming one column and data is written in these columns of pixels in parallel. This data write is performed for the second-half period of one horizontal period. On the other hand, a precharge potential is written on these data lines **107** for the first-half period of the horizontal period.

For this reason, the precharge potential is supplied first and then the data potential is supplied to pixels on the selected horizontal line. On other horizontal lines, only the precharge potential is written (reset), which will be explained later.

The structure of the gate driver **103** will be explained using FIG. 4.

Reference numeral **401** denotes a shift register, **402** denotes a gate enable circuit, **403** denotes a first reset enable circuit, **404** denotes a second reset enable circuit, **405** denotes a gate buffer, **406** denotes a first reset buffer and **407** denotes a second reset buffer.

E1, **E2** are gate enable control lines for odd lines and even lines, respectively, and **R1**, **R2** are a first reset control line and a second reset control line, respectively.

The gate enable circuits of odd lines are connected to the gate enable control line **E1** and the gate enable circuits of even lines are connected to the gate enable control line **E2**. The first reset enable circuits of all lines are connected to the first reset control line **R1** and the second reset enable circuits of all lines are connected to the second reset control line **R2**.

Furthermore, the enable circuits **402**, **403**, **404** of each line are connected to each shift register output V_i ($i=0$ to n) and the shift register output V_i and **E1**, **E2**, **R1**, **R2** control the gate line, first and second reset lines.

The enable circuits **402**, **403**, **404** are AND gates and output H level only when both input signals are H level. Therefore, the enable circuit **402** to which V_i on an odd row is input outputs **E1** when the corresponding V_i is at H level and this **E1** is inverted at the gate buffer **405** and output to the gate line **108**. Therefore, the selection TFT **205** of the pixel circuit is turned ON over a period during which the gate enable control signal **E1** is at H level. On the other hand, the enable circuit **403** outputs **R1** when V_i is at H level, this **R1** is inverted at the first reset buffer **406** and supplied to the first reset line **109**. Therefore, the first reset line **109** becomes L level over a period during which the first reset control signal **R1** is at H level and the reset TFT **203** is turned ON. Furthermore, the enable circuit **404** outputs **R2** when V_i is at H level and this **R2** is supplied from the second reset buffer **407** to the second reset line **110** with the same polarity. Therefore, for the period during which the corresponding V_i is at H level, the first reset line **109** becomes L level over a period during which the second reset control signal **R2** is at H level and the drive control TFT **203** turns ON. Furthermore, the second reset line **110** becomes L level over a period during which the corresponding V_i is at L level and the drive control TFT **204** turns ON.

The driving method in this embodiment will be explained using FIG. 5.

FIG. 5 shows time on the horizontal axis and a line on the vertical axis to illustrate the display status of a frame period. Thus, one-frame period on each line (horizontal scanning line) is divided into a display period during which video data is displayed and a reset period during which the drive TFT is

reset. That is, the reset period of a certain duration is allocated after the display period of the certain duration.

First, video data is sequentially written starting from the first line and lines whose writing has been completed move on to the display period. Then, before writing of video data on all lines is completed after a predetermined period, the pixels on the horizontal line which have already passed the current corresponding to the video data are reset, the display period is closed and the reset period starts. In this embodiment, reset of pixels, that is, reset of the drive TFTs of their respective pixels, is performed sequentially at a plurality of different times.

In FIG. 5, when focused on a segment X-X', video data is written on the k0th line, and the k1th line and the k2th line are reset.

For example, suppose there are 480 horizontal lines in the vertical scanning direction, k0 is the 11th line and the ratios of the display period and reset period are both 50%. In this case, $V_{k0}=V_{11}$ becomes H level for the 11th horizontal scanning period. In this way, reset and data write are performed on the pixels on the 11th horizontal line and the display period starts from the next 12th horizontal scanning period. The display period is 240 horizontal scanning periods and $V_{k0}=V_{11}$ becomes H level for the 252nd horizontal scanning period. In this 252nd horizontal scanning period, reset and data write are performed on the 252nd line, but only reset is performed on the pixels on the 11th line. Therefore, the display of the pixels on the 11th line is finished by this reset and a reset period starts. Then, by setting V11 to H level for an arbitrary even horizontal scanning period (k1th line) between the 254th horizontal scanning period to the 10th horizontal scanning period in the next frame, reset is performed once during the reset period. It is preferable to further increase the number of times reset is performed during this reset period.

Using FIG. 6, FIG. 7 and FIG. 8, the control steps of the data driver 102, gate driver 103 and precharge circuit 104 shown in FIG. 5 will be explained in detail.

In FIG. 6, reference numeral 601 denotes an input pulse which is input to the shift register of the gate driver 103, 602 denotes a clock for shifting the input pulse 601, 603 denotes a shift pulse of the shift register output Vi and this pulse is shifted sequentially in the vertical scanning direction and output to Vi. The period of this clock 602 corresponds to the horizontal scanning period.

Reference numeral 604 denotes the shift register output pulse of the k0th line, 605 denotes the shift register output pulse of the k1st line, 606 denotes the shift register output pulse of the k2nd line and both are active during the X-X' segment. As described above, all output pulses 604, 605 and 606 are pulses for starting a display period during which the first pulse in the figure performs reset or data write, the second pulse is a pulse for starting a reset period during which only reset is performed and the third pulse is a pulse for resetting again during a reset period.

In FIG. 7, reference numeral 701 denotes an output pulse of the shift register outputs V_{k0} , V_{k1} , V_{k2} in the X-X' segment, 702 denotes an output pulse of the shift register outputs V_{k0+1} , V_{k1+1} , V_{k2+1} in the same segment, 703 denotes the enable control line E1 for odd lines, 704 denotes the enable control line E2 for even lines, 705 denotes the first reset control line R1, 706 denotes the second reset control line R2, 707 denotes the precharge control line and 708 denotes the data potential of the data line 107.

FIG. 8 is an operation table of the pixel circuit in FIG. 2 and shows operations of pixels corresponding to their respective

pulse levels when the data driver 102, gate driver 103 and precharge circuit 104 are constructed as shown in this embodiment.

Operations of pixels in FIG. 7 will be explained based on the operation table in FIG. 8.

In FIG. 7, if the input pulse 601 is input so that k0 becomes an odd number, and k1 and k2 become even numbers, since E1 is at H level, R1 and R2 are at H level and precharge is enabled in an X-Y segment which is the first-half period of the X-X' segment, the k0 line corresponds to a reset period from FIG. 8(1). Furthermore, since E2 is shifted from L level to H level, the k1 and k2 lines also correspond to reset periods from FIG. 8(4).

That is, Vi is at H level on any line of k0, k1 and k2, the gate line 108 and the first reset line 109 are at L level and the second reset line 110 is shifted from L level to H level, and therefore the gate potential of the drive TFT 202 is reset to a threshold voltage V_{th} .

In the Y-X' segment which is the second-half period of the X-X' segment, E1 and R2 are at H level, R1 is at L level and precharge is disabled, and therefore from FIG. 8(2), data is only written on k0. That is, on k0, E1 is also at H level for Y-X', and so the selection TFT 205 on the k0 line turns ON and the data potential on the data line 107 is charged in the storage capacitance 206. On the other hand, with regard to the k1, k2 lines, since E2 is at L level for Y-X', the corresponding selection TFT 205 turns OFF and the data potential on the data line 107 is not charged in the storage capacitance 206.

Thus, in the X-X' segment, data is written on the k0 line after reset and only reset is performed on the k1, k2 lines.

In an X'-X" segment, data has been written on the k0 line from FIG. 8(3) as described above, the display of the written data is started. On the other hand, since the k1, k2 lines are in a reset state, the reset period is continued.

Furthermore, in an X'-X" segment, the k0+1 line which is an even line and k1+1, k2+1 which are odd lines are in a state of FIG. 8(4) and FIG. 8(1), respectively, for a first-half period X'-Y', and therefore this period is a reset period and data is only written on the k0+1 line for a second-half period Y'-X".

Driving the pixel circuits sequentially in this way makes it possible to provide the display period and reset period for the frame period as shown in FIG. 5.

In this embodiment, reset is performed three times for one-frame period on each line, but when one reset period cannot be secured sufficiently, performing reset many more times is preferable because in this way the reset potential becomes stable.

Furthermore, by controlling pulse intervals (interval between a pulse for performing reset and data write and the first pulse for performing only reset) of the input pulse 601, it is possible to make the ratio of the display period and reset period variable. FIG. 13 shows a relationship between the data voltage V_d and brightness when the reset period is changed from 25% to 50%, and 75%. When the ratio of the reset period is increased, the display period is shortened, and therefore it is possible to darken the whole while keeping the same gradation characteristic.

When these functions are used together with, for example, the current measuring circuit 115, it is possible to compensate for a leakage current of a TFT by outside light as shown in FIG. 14.

In the pixel circuit in FIG. 2, there are two types of influence of the leakage current; one caused by leakage of the selection TFT 204 and the other caused by a variation of the current characteristic of the drive TFT 202. The former releases a reset load which is stored in the storage capacitance 206, and therefore the gradation voltage is changed with the

lapse of time. Furthermore, the latter acts so that the current of the drive TFT **204** flows more, and so the black level of the video floats and cannot maintain the display quality. That is, the amount of current at the black level increases, producing a certain degree of brightness.

FIG. **14** illustrates a structure of a leakage current correction system when the display of this embodiment is used under illumination. Reference numeral **1401** denotes a current value prediction circuit, **1402** denotes a comparison circuit and **1403** denotes a reset period and reset count control circuit.

In this system, the total value of currents flowing from the input data to the display array can be predicted, and therefore the current value prediction circuit **1401** predicts the current value first. Then, the comparison circuit **1402** compares the predicted current value with the current value from the current measuring circuit **115** and changes the reset period and reset count according to the difference between the predicted value and detected current value.

The control circuit **1403** increases the reset count and thereby repeats reset and charging many times even if the leakage at the reset TFT **203** increases, and in this way it is possible to complement the reset charge. Furthermore, by increasing the reset period, it is possible to cancel the current increase of the drive TFT **202**.

When the comparison circuit **1402** actually detects a current difference, immediately reflecting the current difference on the display would result in flickering, and therefore it is preferable to perform control so that the current difference is provided with hysteresis and the hysteresis is reflected by a Schmitt trigger type.

Furthermore, for these reset periods, the adjusting function on the reset count need not be used for correction of the leakage current. For example, extending the reset period and shortening the display period will reproduce a light-emitting characteristic of a CRT, etc., in a pseudo-form, and can thereby improve viewability of moving images. Thus, by increasing the supply voltage and increasing the current value corresponding in amount to the shortening of the display period, it is possible to use this embodiment for moving image applications such as TV.

Embodiment 2

FIG. **9** shows an internal structure of a data driver **102** according to Embodiment 2. FIG. **9** is an example designed to realize a higher definition display, which expands video signal lines **311** to two sets of video signal lines, namely first video signal lines (R1, G1, B1) and second video signal lines (R2, G2, B2). Using a signal H_i ($i=1$ to n) of one shift register **1** to n , the two sets of video signal lines, three lines each (a total of six lines), are connected to the corresponding data lines **107**. Therefore, when attention is focused on a certain data line, either the first video signal or second video signal is supplied thereto. This allows one pulse of a shift register to sample-and-hold video signals corresponding to twice as many pixels, and can thereby drive a panel with higher resolution.

However, if there are two or more sets of video signal lines **311**, two or more sets of video circuits for generating analog video signals are required, producing variations in the display of adjoining pixels due to variations of both gains.

FIG. **10** is a circuit provided to suppress the display variations, with reference numeral **1001** denoting a first video circuit of the two sets of video circuits, and **1002** denoting a second video circuit. Reference numeral **1003** denotes a first video switch connected to the first video signal line of the two

sets of the video signal lines **311** and **1004** denotes a second video switch connected to the second video signal line.

The output of the video circuit **1001** is connected to terminals **1** of the first and second video switches **1003**, **1004** and the output of the video circuit **1002** is connected to terminals **2** of the first and second video switches **1003**, **1004**. Therefore, the first and second video switches **1003**, **1004** can select the first video signal and second video signal alternately and select video signals which are different from each other. For example, when attention is focused on the first data line and the second data line of the same color adjoining the first data line, it is possible to select video signals alternately, for example, by supplying the first video signal to the first data line and supplying the second video signal to the second data line.

FIG. **11** is a switching timing chart of the video switches **1003**, **1004**. Reference numeral **1101** denotes an input pulse to be input to a shift register **401** of a gate driver **103**, **1102** denotes a clock to shift the input pulse **1101**, **1103** denotes an input pulse to be input to a shift register **301** of a data driver **102**, **1104** denotes a switching signal for switching between the video switches **1103** and **1104**, **1105** denotes a video signal on a first video signal line and **1106** denotes a video signal on a second video signal line.

Switching is performed alternately between an odd line and even line, between an odd frame and an even frame at the timing of the switching signal **1104**. In this way, signals of the video circuits **1001** and **1002** are alternately written on pixels for every frame, and therefore display variations are smoothed. That is, as shown in FIG. **11**, the first video signal and second video signal are supplied alternately such as A1, A2, A1, A2, . . . , on the line on which the n th frame exists, and the first video signal and second video signal are supplied alternately such as A2, A1, A2, A1, . . . , on the next line. Then, in the next ($n+1$)th frame, the first video signal and second video signal are supplied alternately such as A2, A1, A2, A1, . . . , on a certain line, and the first video signal and second video signal are supplied alternately such as A1, A2, A1, A2, . . . , on the next line.

Furthermore, by also performing switching for every line, it is possible to suppress flickering and prevent display variations from becoming noticeable even if the output characteristics of the video circuits **1001**, **1002** differ from each other. Furthermore, this circuit may also be incorporated in the control circuit **106** or formed on a glass substrate.

Embodiment 3

FIG. **15** is a conventionally known pixel circuit, which includes two TFTs, namely a selection TFT **205** and a drive TFT **202**, and one storage capacitance **206** in addition to an organic EL element **201**. The source of the selection TFT **205** is connected to a data line **107**, the drain is connected to the gate of the drive TFT **202** and the gate is connected to a gate line **108**. Furthermore, a non-fixed potential end of the storage capacitance **206** whose other end is connected to a fixed potential line **212** is connected to the gate of the drive TFT **202**. The source of the drive TFT **202** is connected to a power line **211** and the drain is connected to the anode of the organic EL element **201**. The cathode of the organic EL element **201** is connected to a cathode power supply.

In this circuit, too, as with the above described embodiment, a precharge voltage is supplied to the data line **107** for a first-half period of one horizontal period and data is written only on a horizontal scanning line on which data is written for a second-half period.

In this embodiment, there is no reset line, and therefore the enable circuits **403**, **404** in FIG. **4** are not necessary and only the enable circuit **402** should be provided. Furthermore, the R1, R2 in FIG. **7** are not necessary either.

When such a circuit is used, it is also possible to make a reset time variable as in the case of the above described embodiment.

The reset operation of the present invention is not limited to the pixel circuits in FIG. **2** and FIG. **15**, but may also be applied to various pixel circuits such as the pixel circuit described in FIG. **12** or pixels of opposed electrodes between which a liquid crystal, etc., is sandwiched.

Furthermore, the structure of the gate driver is not limited to the one shown in FIG. **4**. For example, as shown in FIG. **16**, it is also possible to use three or more enable control lines. That is, in the case of the structure in FIG. **16** using three enable control lines, an enable circuit **402** is connected to any identical enable control line of the three enable control lines E1, E2, E3 on every third line, one of the three enable control lines may be selected for video writing and at least the remaining one may be selected for reset writing. Using such a gate driver, the same reset operation as that described above can also be realized.

PARTS LIST

E1 gate enable control line
 E2 gate enable control line
 E3 gate enable control line
 R1 first reset control line
 R2 second reset control line
 101 active matrix type display
 102 data driver
 103 gate driver (selection driver)
 104 precharge circuit
 105 display device
 106 control circuit
 107 data line
 108 gate line (selection line)
 109 first reset line
 110 first reset line
 112 control bus
 113 control bus
 115 current measuring circuit
 201 organic EL element
 202 drive TFT
 203 reset TFT
 204 drive control TFT
 205 selection TFT
 206 storage capacitance
 207 reset capacitance
 211 power line
 212 fixed potential line
 301 shift register
 302 video switch
 310 data line
 311 video signal line
 311 video signal lines
 312 precharge control line
 313 precharge line
 320 select line
 330 auto-zero illumination line
 340 illumination line
 355 capacitance
 365 TFT
 370 TFT
 375 TFT

380 OLED
 401 shift register
 402 gate enable circuit
 403 first reset enable circuit
 404 second reset enable circuit
 405 gate buffer
 406 first reset buffer
 407 second reset buffer
 601 input pulse
 602 clock
 603 shift pulse of shift register
 604 shift register output pulse
 605 shift register output pulse
 606 shift register output pulse
 701 output pulse
 702 output pulse
 703 enable control line
 704 enable control line
 705 first reset control line
 706 second reset control line
 707 precharge control line
 708 data potential
 1001 first video circuit
 1002 second video circuit
 1003 first video circuit
 1004 second video switch
 1101 input pulse
 1102 clock
 1103 input pulse
 1104 switching signal
 1105 video signal
 1106 video signal
 1401 current value prediction circuit
 1402 comparison circuit
 1403 reset period

The invention claimed is:

1. An active matrix type display device comprising:

an active matrix type display array made up of pixel circuits arranged in a row and column matrix form, each pixel circuit includes a current-driven diode type light-emitting element and a plurality of thin-film transistor for controlling the diode type light-emitting element;

a data line provided for each column of the matrix for supplying a data signal to the pixel circuits on the corresponding column;

a data driver for controlling the supply of the data signal to the data line;

a gate line provided for each row of the matrix for supplying a selection signal to pixel circuits on the corresponding row;

a gate driver for supplying the selection signal to the gate line; and

a control circuit for controlling the data driver and gate driver, wherein the data driver switches a plurality of sets of video signals alternately and supplies the video signals to the data line,

wherein the data driver further switches between the plurality of sets of video signals at least for each frame or each line and supplies the video signals to the data line,

wherein the pixel circuit comprises:

a storage capacitance, the potential at one end of which is fixed to a predetermined potential;

a gate transistor, having one non-control terminal connected to a non-fixed potential terminal of the storage capacitance, an other non-control terminal connected to the data line and a control terminal connected to the gate line;

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a drive transistor, having its control terminal connected to a non-fixed potential terminal of a reset capacitance and the non-control terminal connected to a power line, for controlling a drive current to the diode type light-emitting element;

an ON control transistor, having its control terminal connected to the ON line, one non-control terminal connected to the other non-control terminal of the drive transistor, and the other non-control terminal connected to the diode type light-emitting element, for controlling ON/OFF of the drive current of the diode type light-emitting element; and

a reset transistor, having its control terminal connected to a first reset line, one non-control terminal connected to the other non-control terminal of the drive transistor and the non-control terminal of the ON control transistor, and an other non-control terminal connected between the control terminal of the drive transistor and the non-fixed potential terminal of the reset capacitance.

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2. The active matrix type display device according to claim 1:

wherein the plurality of sets of video signals include a first set and a second set,

5 in the data driver, for an odd frame, the first data line on an odd line supplies the first set video signals, the second data line of the same color adjoining the first data line supplies the second set video signals, the first data line on an even line supplies the second set video signals and the second data line supplies the first set video signals, and for an even frame, the first data line on an odd line supplies the second set video signals, the second data line supplies the first set video signals, the first data line on an even line supplies the first set video signals and the second data line supplies the second set video signals.

3. The active matrix type display device according to claim 1, wherein the diode type light-emitting element is an organic EL element.

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